

Ain Shams University
Faculty of Science
Physics department



Studies on the Physical Properties of Cadmium Telluride Nanostructure Thin Films

A thesis

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(Solid State Physics)

By

Sohaila Zaghloul Noby Mohammed

Ain Shams University
(BSc physics 2007)

Supervisors

Prof. Dr. Mohammed Bahaa El-Deen
Professor of Solid State physics
Physics Department, Faculty of Science-Ain Shams University

Prof. Dr. Mahmoud Mohamed Mohamed El-Nahass
Professor of Solid State physics
Physics Department, Faculty of Education-Ain Shams University

Dr. Gamal Mahmoud Youssef
Associated Professor of Solid State physics
Physics Department, Faculty of Science-Ain Shams University

Dr. Samia Ahmed Abdel-Kawy Gad
Associated Professor of Solid State physics
Physics Department, National Research Centre

2014



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Faculty of Science

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APPROVAL SHEET

Title of the M.Sc. Thesis

***Studies on the Physical Properties of Cadmium
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Name of the Candidate

Sohaila Zaghloul Noby Mohammed

Supervisors

(Signature)

Prof. Dr. Mahmoud Mohamed El-Nahass

(.....)

**Physics Department
Faculty of Education
Ain Shams University**

Ass.Prof. Gamal Mahmoud Ali Youssef

(.....)

**Physics Department
Faculty of Education
Ain Shams University**

Ass.Prof. Samia Ahmed Abdel-Qawy Gad

(.....)

**Physics Department
National Research Centre**



Name: Sohaila Zaghloul Noby Mohammed

Degree: Master

Department: Physics – Solid State Physics

Faculty: Science

University: Ain Shams University

Graduation Date: 2007

Registration Date: 2011

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"رَبِّ قَدْ آتَيْتَنِي مِنَ الْمُلْكِ وَعَلَّمْتَنِي مِنْ تَأْوِيلِ الْأَحَادِيثِ ۚ فَاطِرَ
السَّمَاوَاتِ وَالْأَرْضِ أَنْتَ وَلِيِّي فِي الدُّنْيَا وَالْآخِرَةِ ۖ تَوَفَّنِي مُسْلِمًا
وَالْحَقْنِي بِالصَّالِحِينَ"

سورة يوسف (١٠١)

*Great Thanks and love to my Father, my Mather,
my Husband Dr/ Hytham Refaiy, My sisters
Walaa,Sara, Salma and my only brother
Mohammed.*

Contents

Contents

Acknowledgment	I
List of Figures	III
List of Tables	IX
Published Papers	XI
Abstract	
Chapter 1: Introduction	
1.1 Nanoscience.....	1
1.2. Semiconductor nanoparticles.....	2
1.3. Cadmium telluride	2
1.4. Thesis outlines.....	3
Chapter 2: Theoretical background and literature review	5
2.1. Structure of Cadmium Telluride.....	5
2.2 What makes nano-semiconductors properties superior than their counterparts in microstructure materials?.....	7
2.2.1. Quantum confinement	7
2.2.2. Bohr radius of the Exciton.....	10
2.2.2.1. Weak confinement regime	12
2.2.2.2. Intermediate confinement regime.....	13
2.2.2.3. Strong confinement regime.....	13
2.2.2. Surface to volume ratio.....	14
2.3. Optical characterization	15
2.3.1. Optical constants.....	16
2.3.2. Absorption process.....	17
2.3.2.1. Absorption at fundamental absorption edge.....	18
2.3.2.1.1. Direct transition.....	19



2.3.2.1.2. Indirect transition.....	19
2.3.3. Dispersion in semiconductors.....	21
2.3.3.1. Single effective oscillator model.....	21
2.3.3.2. Dielectric characterizations.....	21
2.4. Junctions in semiconductor devices.....	21
2.4.1. Schottky junction.....	22
2.4.2. Ohmic contact.....	23
2.4.3. Homojunction.....	24
2.4.4. Heterojunction	25
2.5. The diode equation.....	26
2.5.1. Ideality factor.....	28
2.5.1.1. Slope method.....	28
2.6. Some models for the electrical transport mechanisms in p-n junctions and experimental methods of identifying the mechanism.....	29
2.6.1. Introduction.....	30
2.6.2. Some mechanism.....	31
2.7. Literature review.....	32
Chapter 3: Experimental work	37
3.1. How to get at nano-scale?.....	37
3.1.1. The ‘top-down’ approach.....	38
3.1.2. The ‘bottom-up approach.....	38
3.2. Methods of Synthesis of Powder of CdTe QDs.....	39
3.2.1. Methodology.....	41
3.3 Thin film preparation	42
3.4. Techniques of Thin film Measurements.....	43



3.4.1. Quartz Crystal Thickness Monitor.....	43
3.4.2. Interferometric Method.....	44
3.5. Characterization techniques	47
3.5.1. UV-Visible Absorption Spectroscopy.....	47
3.5.2. X-ray diffraction.....	47
3.5.3. Transmission electron microscope.....	49
3.6. Optical measurement.....	49
3.6.1. UV-Vis-NIR spectroscopy.....	49
3.7. Heterojunction formation and measurements.....	53
3.7.1 Preparation of CdTe QDs/p-Si heterojunction diodes.....	53
 Chapter 4: Results and Discussion	 54
4.1 Structural characterization	54
4.1.1. X-ray diffraction.....	54
4.1.2. Transmission electron microscope.....	59
4.2. Optical Transition.....	64
4.2.1. Absorption coefficient	64
4.2.2. Types of transition.....	66
4.2.2.1. Direct transition.....	66
4.2.2.2 Indirect transition.....	69
4.2.2. Urbach energy.....	71
4.3. Optical Constants of CdTe QD's Thin Films.....	72
4.4. Single oscillator parameters of CdTe QDs thin film.....	74
4.5. Coordination number.....	76



4.6. Lattice dielectric constant and carrier concentration.....	78
4.7. Electrical conduction mechanisms of CdTe quantum....	80
dots/p-Si heterojunction.....	
4.7.1. Dark electrical properties.....	80
4.7.1.1. Dark current parameters.....	80
4.7.1.1.1. Rectification ratio.....	80
4.7.1.1.2. Series resistance	82
4.7.1.1.3. Shunt resistance.....	82
4.7.2. Dark conduction mechanisms.....	83
4.7.2.1. At low voltage region I [$V \leq 0.3V$].....	84
4.7.2.2. At Region II ($0.5 \leq V \leq 0.9$ volt).....	85
4.7.2.3. The third region ($0.95 \leq V \leq 1.5$ volt).....	89
4.7.2.4. Activation energy	92
4.7.2.5. The dark reverse characteristics of Au / CdTe QDs / p-Si / Al heterojunction device.....	94
Conclusion.....	97
References.....	99
Arabic Summary.....	i



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